

### Vishay General Semiconductor

### Standard Avalanche SMD Rectifier



DO-214AC (SMA)

PRIMARY CHARACTERISTICS						
$I_{F(AV)}$	1.5 A					
$V_{RRM}$	200 V to 1600 V					
I <sub>FSM</sub>	30 A					
I <sub>R</sub>	1.0 μΑ					
$V_{F}$	1.15 V					
E <sub>R</sub>	20 mJ					
T <sub>J</sub> max.	150 °C					

#### **FEATURES**

- · Low profile package
- · Ideal for automated placement
- · Controlled avalanche characteristics
- Glass passivated junction
- · Low reverse current
- · High surge current capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Solder dip 260 °C, 40 s
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

#### **TYPICAL APPLICATIONS**

For use in generell purpose rectification of power supplies, inverters, converters and freewheeling diodes for consumer, automotive and telecommunication.

#### **MECHANICAL DATA**

Case: DO-214AC (SMA)

Epoxy meets UL 94 V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC-Q101 qualified), meets JESD 201 class 2 whisker test

Note:

• BYG10Y for commercial grade only

Polarity: Color band denotes the cathode end

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	BYG10D	BYG10G	BYG10J	BYG10K	BYG10M	BYG10Y	UNIT
Device marking code		BYG10D	BYG10G	BYG10J	BYG10K	BYG10M	BYG10Y	
Maximum repetitive peak reverse voltage	$V_{RRM}$	RM 200 400 600 800 1000 1600				1600	V	
Average forward current	I <sub>F(AV)</sub>	1.5						Α
Peak forward surge current 10 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	30						Α
Pulse energy in avalanche mode, non repetitive (inductive load switch off) I <sub>(BR)R</sub> = 1 A, T <sub>J</sub> = 25 °C (for BYG10D-BYG10M)	E <sub>R</sub>	20						mJ
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 55 to + 150						°C

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## **BYG10D thru BYG10Y**

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)										
PARAMETER	TEST CONDITIONS		SYMBOL	BYG10D	BYG10G	BYG10J	BYG10K	BYG10M	BYG10Y	UNIT
Maximum instantaneous forward voltage (1)	I <sub>F</sub> = 1 A I <sub>F</sub> = 1.5 A	T <sub>J</sub> = 25 °C	V <sub>F</sub>	1.1 1.15						<b>V</b>
Maximum DC reverse current	$V_R = V_{RRM}$	T <sub>J</sub> = 25 °C T <sub>J</sub> = 100 °C	I <sub>R</sub>	1 10						μΑ
Maximum reverse recovery time	$I_F = 0.5 A, I_R$ $I_{rr} = 0.25 A$	= 1.0 A,	t <sub>rr</sub>	4				μs		

#### Note:

(1) Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL BYG10D BYG10G BYG10J BYG10K BYG10M BYG10Y						UNIT
Typical thermal resistance, junction to lead	$R_{ heta JL}$	25					°C/W
Typical thermal resistance, junction to ambient	$R_{ hetaJA}$	150 <sup>(1)</sup> 125 <sup>(2)</sup> 100 <sup>(3)</sup>					°C/W

#### Notes:

- (1) Mounted on epoxy-glass hard tissue
- (2) Mounted on epoxy-glass hard tissue, 50  $\text{mm}^2$  35  $\mu\text{m}$  Cu
- (3) Mounted on Al-oxide-ceramic (Al<sub>2</sub>O<sub>3</sub>), 50 mm<sup>2</sup> 35  $\mu$ m Cu

ORDERING INFORMATION (Example)									
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE					
BYG10D-E3/TR	0.064	TR	1800	7" diameter plastic tape and reel					
BYG10D-E3/TR3	0.064	TR3	7500	13" diameter plastic tape and reel					
BYG10DHE3/TR (1)	0.064	TR	1800	7" diameter plastic tape and reel					
BYG10DHE3/TR3 (1)	0.064	TR3	7500	13" diameter plastic tape and reel					

#### Note:

(1) AEC-Q101 qualified



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### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

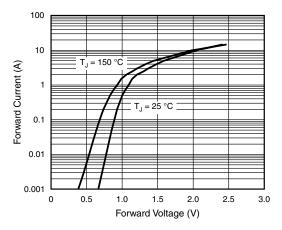


Figure 1. Forward Current vs. Forward Voltage

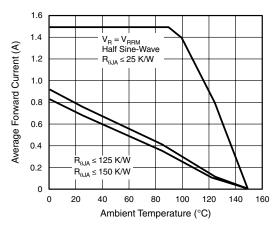


Figure 2. Max. Average Forward Current vs. Ambient Temperature

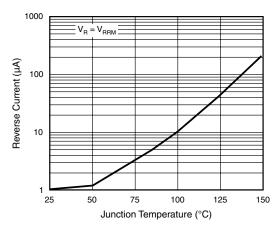


Figure 3. Reverse Current vs. Junction Temperature

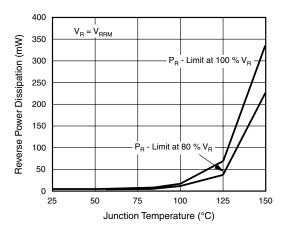


Figure 4. Max. Reverse Power Dissipation vs. Junction Temperature

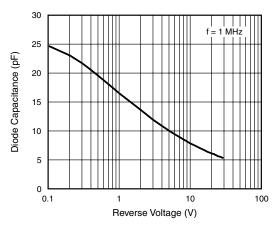


Figure 5. Diode Capacitance vs. Reverse Voltage

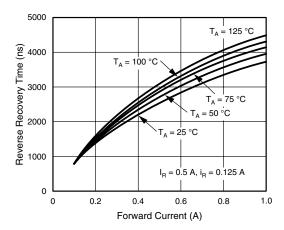


Figure 6. Reverse Recovery Time vs. Forward Current

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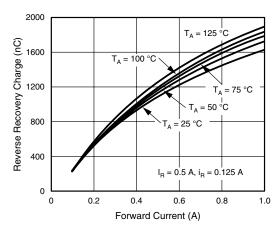
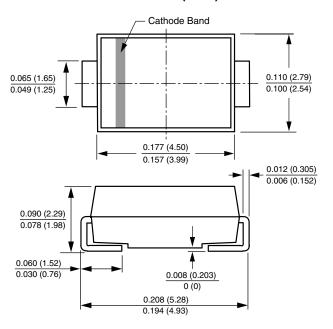


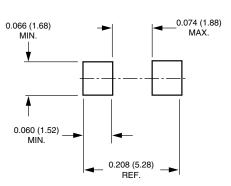
Figure 7. Reverse Recovery Charge vs. Forward Current

#### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

#### DO-214AC (SMA)



#### **Mounting Pad Layout**



# **Legal Disclaimer Notice**



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